TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

TC74LCX32F, TC74LCX32FN, TC74LCX32FT

LOW VOLTAGE QUAD 2-INPUT OR GATE WITH 5V TOLERANT INPUTS AND OUTPUTS

The TC74LCX32 is a high performance CMOS 2-INPUT OR GATE. Designed for use in 3.3 Volt systems, it achieves high speed operation while maintaining the CMOS low power dissipation.

The device is designed for low-voltage (3.3V) V_{CC} applications, but it could be used to interface to 5V supply environment for inputs.

All inputs are equipped with protection circuits against static discharge.

FEATURES

Low voltage operation : V_{CC} = 2.0~3.6V

High speed operation : t_{pd} = 5.5ns (Max.)

 $(V_{CC} = 3.0 \sim 3.6 V)$

• Output current : $|I_{OH}|/I_{OL} = 24$ mA (Min.)

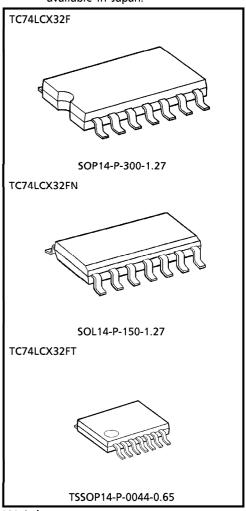
 $(V_{CC} = 3.0V)$

Latch-up performance : ±500mA

Available in JEDEC SOP, JEITA SOP and TSSOP

- Power down protection is provided on all inputs and outputs.
- Pin and function compatible with the 74 series (74AC/VHC/HC/F/ALS/LS etc.) 32 type.

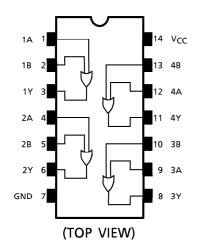
(Note) The JEDEC SOP (FN) is not available in Japan.



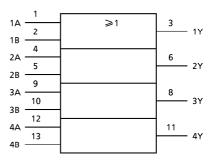
Weight

SOP14-P-300-1.27 : 0.18g (Typ.) SOL14-P-150-1.27 : 0.12g (Typ.) TSSOP14-P-0044-0.65 : 0.06g (Typ.)

PIN ASSIGNMENT



IEC LOGIC SYMBOL



TRUTH TABLE

INP	UTS	OUTPUTS		
Α	В	Υ		
L	L	L		
L	Н	Н		
Н	L	Н		
Н	Н	Н		

MAXIMUM RATINGS

PARAMETER	SYMBOL	RATING	UNIT	
Supply Voltage Range	Vcc	- 0.5~7.0	V	
DC Input Voltage	VIN	-0.5~7.0	V	
DC Output Valtage	\/ - · · =	-0.5~7.0 (Note 1)	٧	
DC Output Voltage	Vout	-0.5~V _{CC} +0.5 (Note 2)		
Input Diode Current	ΙΚ	– 50	mA	
Output Diode Current	^I ОК	± 50 (Note 3)	mA	
DC Output Current	IOUT	± 50	mA	
Power Dissipation	PD	180	mW	
DC V _{CC} /Ground Current	ICC / IGND	± 100	mA	
Storage Temperature	T _{stg}	- 65∼150	°C	

(Note 1) VCC = 0V (Note 2) High or Low State. $I_{\mbox{OUT}}$ absolute maximum rating must be observed.

(Note 3) VOUT < GND, VOUT > VCC

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RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	RATING	UNIT
Supply Valtage	Van	2.0~3.6	V
Supply Voltage	Vcc	1.5~3.6 (Note 4)]
Input Voltage	VIN	0~5.5	٧
Output Valtage	VOUT	0~5.5 (Note 5)	_ v
Output Voltage		0~ V _{CC} (Note 6)	
Output Current	10/10.	± 24 (Note 7)	A
Output Current	OH/IOL	± 12 (Note 8)	mA
Operating Temperature	T _{opr}	- 40~85	°C
Input Rise And Fall Time	dt/dv	0~10 (Note 9)	ns / V

(Note 4) Data Retention Only

(Note 5) VCC = 0V

(Note 6) High or Low State

(Note 7) $V_{CC} = 3.0 \sim 3.6V$ (Note 8) $V_{CC} = 2.7 \sim 3.0V$

(Note 9) $V_{IN} = 0.8 \sim 2.0 \text{V}$, $V_{CC} = 3.0 \text{V}$

ELECTRICAL CHARACTERISTICS

DC characteristics (Ta = $-40 \sim 85$ °C)

PARAN	ЛЕТЕR	SYMBOL	TEST CON	TEST CONDITION VCC (MIN.	MAX.	UNIT	
Input	"H" Level	V_{IH}			2.7~3.6	2.0	_	V	
Voltage	"L" Level	V _{IL}			2.7~3.6	_	0.8	V	
			$I_{OH} = -100 \mu A$	2.7~3.6	V _C C - 0.2	_			
	"H" Level	Voн	VIN = VIH or VIL	$I_{OH} = -12mA$	2.7	2.2	_	v	
				I _{OH} = - 18mA	3.0	2.4	_		
Output				$I_{OH} = -24mA$	3.0	2.2	_		
voitage	Voltage			I _{OL} = 100μA	2.7~3.6	_	0.2		
"L" Level	VOL	V _{IN} = V _{IL}	I _{OL} = 12mA	2.7	_	0.4			
	L Level	VOL	VIN - VIL	I _{OL} = 16mA	3.0	_	0.4		
			I _{OL} = 24mA	3.0	_	0.55			
Input Leaka	ge Current	I _{IN}	$V_{1N} = 0 \sim 5.5V$		2.7~3.6	_	± 5.0	μ A	
Power Off L Cuurent	eakage	lOFF	V _{IN} / V _{OUT} = 5.5V		0	_	10.0	μΑ	
Quiescent Su	ıpply		$V_{IN} = V_{CC}$ or GND		V _{IN} = V _{CC} or GND		_	10.0	
Current	-	ICC	$V_{IN} / V_{OUT} = 3.6 \sim 5.5 V$		2.7~3.6	_	± 10.0	μ A	
Quiescent In Input	I _{CC} Per	ΔΙCC	V _{IH} = V _{CC} – 0.6V		2.7~3.6		500	μΑ	

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AC characteristics ($Ta = -40 \sim 85^{\circ}C$)

PARAMETER	SYMBOL	TEST CONDITION	V _{CC} (V)	MIN.	MAX.	UNIT
Propagation Delay	t _{pLH}	(Fig.1, 2)	2.7	_	6.2	ns
Time	t _{pHL}	(Fig. 1, 2)	3.3 ± 0.3	1.5	5.5	113
Output To Output	tosLH	(Note 10)	2.7	_	-	nc
Skew	tosHL	(Note 10	3.3 ± 0.3	_	1.0	ns

(Note 10) Parameter guaranteed by design. $(t_{OSLH} = |t_{pLHm} - t_{pLHn}|, t_{OSHL} = |t_{pHLm} - t_{pHLn}|)$

DYNAMIC SWITCHING CHARACTERISTICS (Ta = 25°C, Input $t_r = t_f = 2.5$ ns, $C_L = 50$ pF, $R_L = 500\Omega$)

PARAMETER	SYMBOL	TEST CONDITION	V _{CC} (V)	TYP.	UNIT
Quiet Output Maximum Dynamic VOL	V _{OLP}	V _{IH} = 3.3V, V _{IL} = 0V	3.3	0.8	٧
Quiet Output Minimum Dynamic VOL	V _{OLV}	V _{IH} = 3.3V, V _{IL} = 0V	3.3	0.8	\ \

CAPACITIVE CHARACTERISTICS (Ta = 25°C)

PARAMETER	SYMBOL	TEST CONDITION		V _{CC} (V)	TYP.	UNIT
Input Capacitance	C _{IN}			3.3	7	рF
Output Capacitance	COUT	_		0	8	pF
Power Dissipation Capacitance	C _{PD}	f _{IN} = 10MHz	(Note 11)	3.3	25	pF

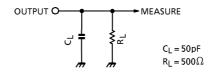
(Note 11) CpD is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

ICC (opr.) = CpD · VCC · f_{IN} + I_{CC} / 4 (per gate)

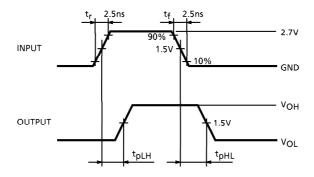
TEST CIRCUIT

Fig.1



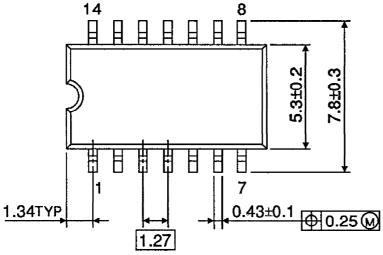
AC WAVEFORM

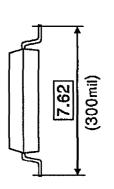
Fig.2 t_{pLH}, t_{pHL}

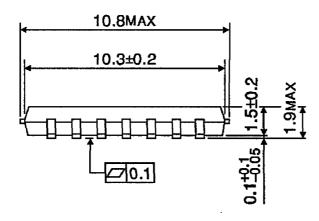


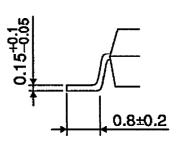
Unit: mm

PACKAGE DIMENSIONS SOP14-P-300-1.27



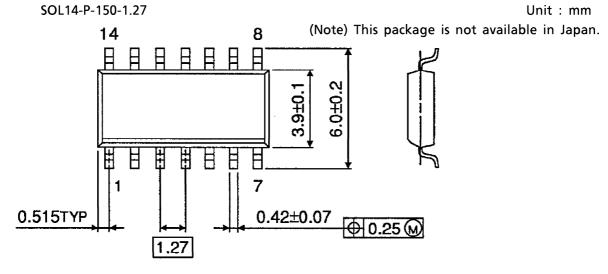


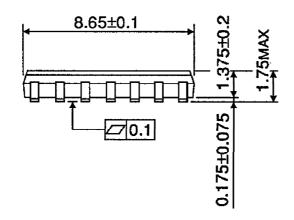


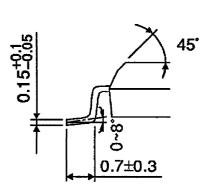


Weight: 0.18g (Typ.)

PACKAGE DIMENSIONS





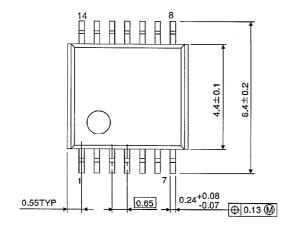


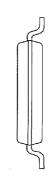
Weight: 0.12g (Typ.)

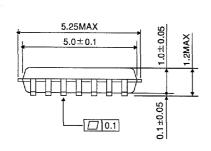
PACKAGE DIMENSIONS

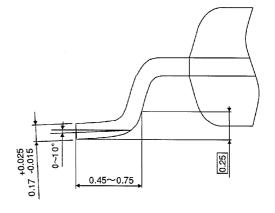
TSSOP14-P-0044-0.65

Unit: mm









Weight: 0.06g (Typ.)

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